

SANYO Semiconductors DATA SHEET

DSF10T — Diffused Junction Type Silicon Diode 1.0A Power Rectifier

Features

· Meets automatic mounting requirements.

· Plastic molded structure (small size).

• Peak reverse voltage: V_{RM}=100 to 200V.

• Average rectified current : IO=1.0A.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	DSF10TB DSF10TC		Unit
Peak Reverse Voltage	VRM		100	200	٧
Average Rectified Current	IO	Ta=25°C	1.	Α	
Surge Forward Current	IFSM	50Hz sine wave, 1cycle	4	Α	
Junction Temperature	Tj		15	°C	
Storage Temperature	Tstg		-40 to	°C	

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Forward Voltage	٧F	I _F =1.0A			1.0	V
Reverse Current	IR	V _R : At each V _{RM}			10	μΑ

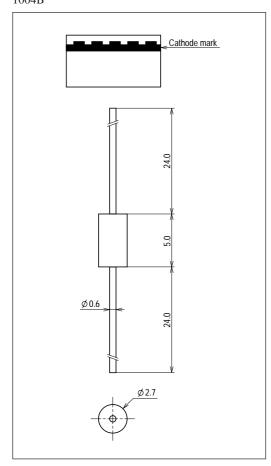
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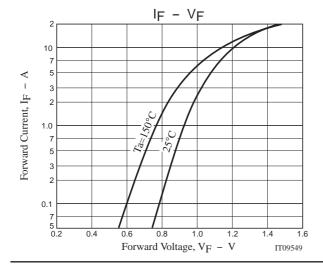
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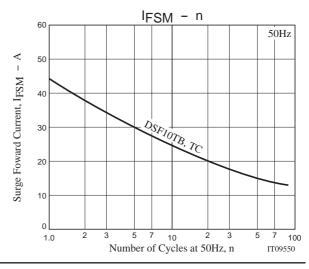
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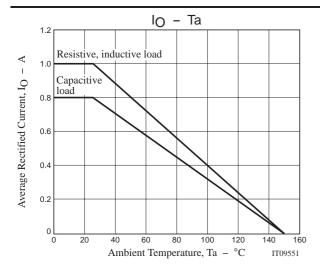
Package Dimensions

unit : mm (typ) 1004B









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